

# BA157-BA159

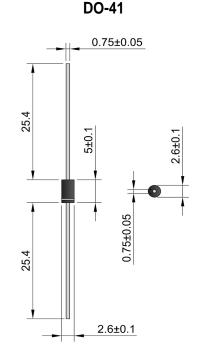
1.0A FAST RECOVERY DIODE

### Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

## **Mechanical Data**

- Case: DO-41, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.35 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Lead Free: For RoHS / Lead Free Version



## Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	BA157	BA158	BA159	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	400	600	1000	V
RMS Reverse Voltage	VR(RMS)	280	420	700	V
Average Rectified Output Current (Note 1) $@T_A = 55^{\circ}C$	lo	1.0			А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	IFSM	30			A
Forward Voltage $@I_F = 1.0A$	Vfm	1.2			V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	Iгм	5.0 100			μA
Reverse Recovery Time (Note 2)	t <sub>rr</sub>	150	250	500	nS
Typical Junction Capacitance (Note 3)	CJ	12			pF
Typical Thermal Resistance Junction to Ambient (Note 1) Typical Thermal Resistance Junction to Lead (Note 1)	R JA R JL	55 25			°C/W
Operating Temperature Range	TJ	-65 to +125			°C
Storage Temperature Range	Тѕтс	-65 to +150			°C

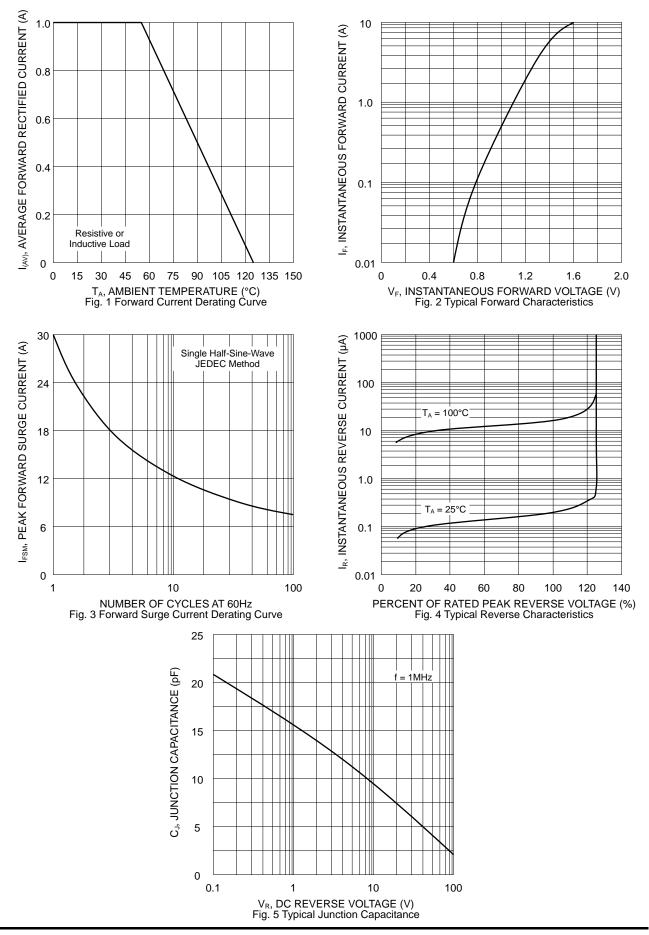
Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

2. Measured with  $I_{\text{F}}$  = 0.5A,  $I_{\text{R}}$  = 1.0A,  $I_{\text{RR}}$  = 0.25A.

3. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.

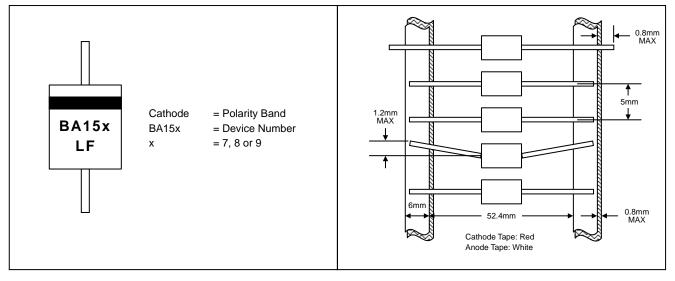


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### MARKING INFORMATION



**TAPING SPECIFICATIONS** 

#### PACKAGING INFORMATION

